



UNIU-NE Technology CO., LTD

浙江宇力微新能源科技有限公司



U2103/6 Data Sheet

V 1.1

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High Current IO+/- 0.5/0.8A HALF-BRIDGE DRIVER

General Description

The U2103/U2106 Fully operated to +600V is high voltage, high speed power MOSFET and IGBT driver with dependent high and low side referenced output channels.

The logic input is compatible with standard CMOS or LSTTL output, down to 3.3V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 600 volts.

Product Summary

V _{OFFSET}	600V max
I _{O+/-}	0.5A / 0.8A
V _{OUT}	9V ~ 21V
ton/off (typ.)	680/320 & 120/260ns
Deadtime (typ.)	560 & 50ns
Work Tem	-40 ~ 150 °C

Products Information

Base Part Number	Package Type	Standard OUT		V _{OFFSET}	Logic Control
		IO+	IO-		
U2103	SOP8	0.5A	0.8A	600V	HIN & $\overline{\text{LIN}}$
U2106	SOP8	0.5A	0.8A	600V	HIN & LIN

Key Features

- Floating channel designed for bootstrap operation
- Fully operational to +600V
- Tolerant to negative transient voltage dV/dt immune
- Gate drive supply range from 9 to 21V
- Undervoltage lockout
- 3.3V, 5V and 15V input logic compatible
- Cross-conduction prevention logic
- Matched propagation delay for both channels

Applications

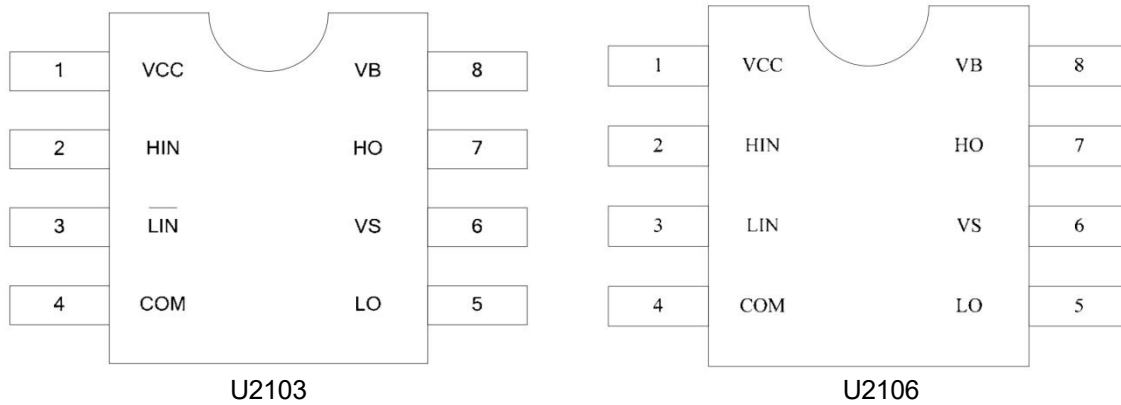
- Home appliances
- Industrial applications and drives
- Motor drivers
- DC- AC Converter, PMDC and PMAC motors
- Induction heating
- HVAC

Packages



8-Lead SOP

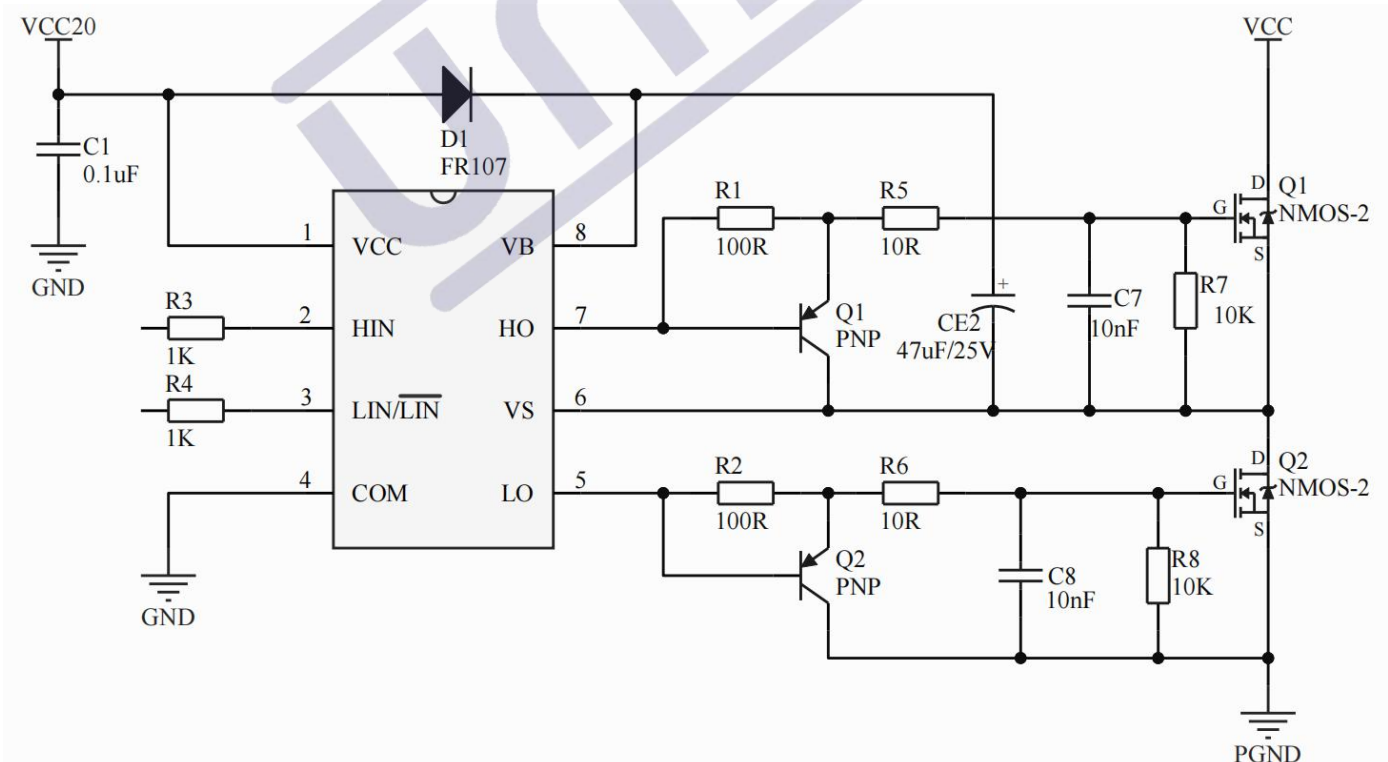
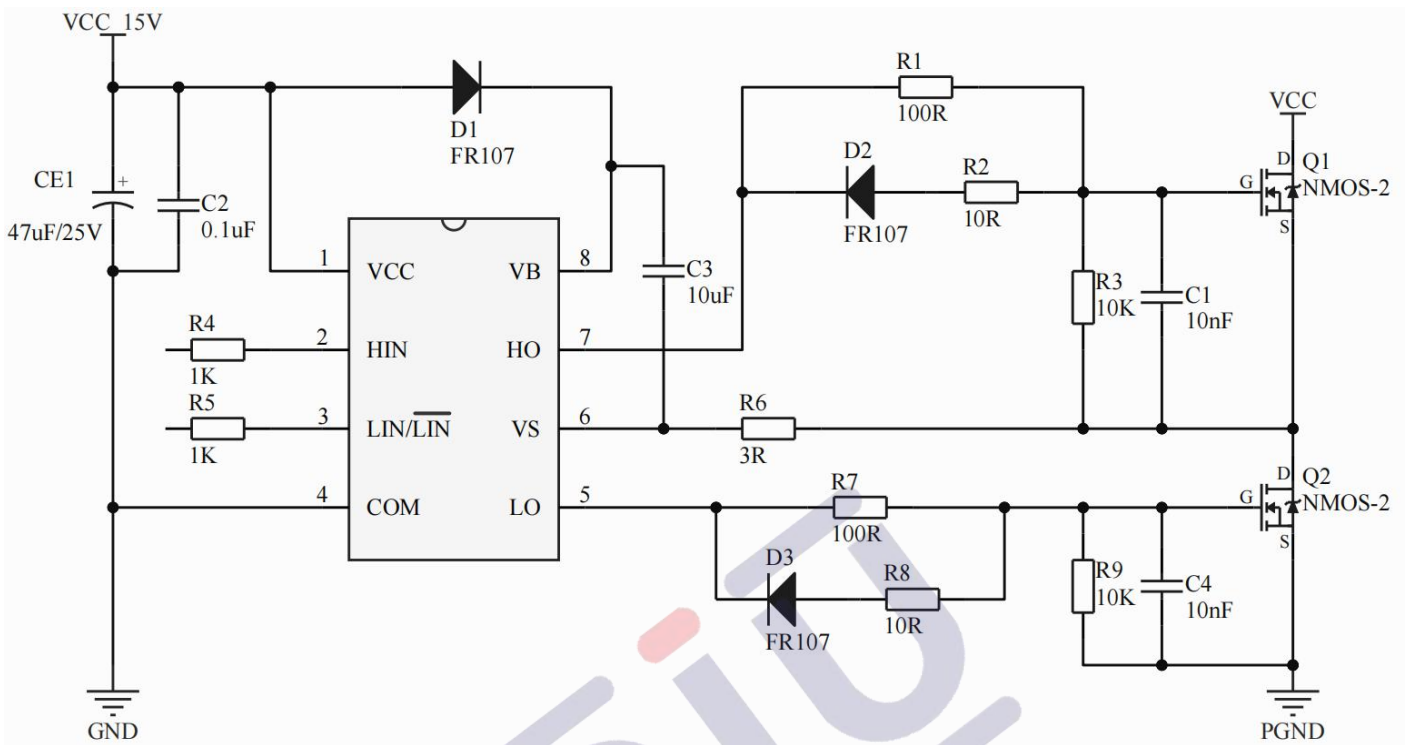
Pin Assignments



Pin Function

Number	Symbol	Description
1	VCC	Low side and logic fixed supply
2	HIN	Logic input for high side gate driver outputs (HO), in phase
3	LIN	Logic input for low side gate driver outputs (LO), in phase
	$\overline{\text{LIN}}$	Logic input for low side gate driver outputs (LO), out of phase
4	COM	Low side return
5	LO	Low side gate drive output
6	VS	High side floating supply return
7	HO	High side gate drive output
8	VB	High side floating supply

Typical Connection



Much Big POWER application

1.版本记录

DATE	REV.	DESCRIPTION
2018/04/19	1.0	First Release
2020/05/21	1.1	Change the package

2.免责声明

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